## NSN 5961-01-191-6849

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View Online at https://aerobasegroup.com/nsn/5961-01-191-6849 **Inclosure Material:** Metal **Overall Length:** 0.650 inches **Overall Diameter:** 0.215 inches **End Application:** An/grc206 **Mounting Method:** Terminal Voltage Rating In Volts Per Characteristic: 50.0 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 nanoamperes repetitive peak forward current peak **Maximum Operating Tempurature Per Measurement Point:** 85.0 degrees celsius ambient air **Special Features:** With fiberoptic terminal **Test Data Document:** 37695-813820 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: